

## **Random Si distribution between the T-site and M-site of MgAl<sub>2</sub>O<sub>4</sub>-spinel at high P-T conditions**

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MgAl<sub>2</sub>O<sub>4</sub>-spinel is geologically important. Its cation order-disorder behaviour can affect a large range of physical and chemical properties, so that it has been extensively investigated. How its minor component such as SiO<sub>4</sub> is hosted by the crystal structure is largely unknown.

In this study, we synthesized a series of Si-bearing MgAl<sub>2</sub>O<sub>4</sub>-spinel at 1500-1650 °C and 3-6 GPa. These spinels had SiO<sub>2</sub> contents up to ~1.03 wt%, and showed a substitution mechanism of Si<sup>4+</sup> + Mg<sup>2+</sup> = 2Al<sup>3+</sup>.

Unpolarized Raman spectra were collected from the experimental products, and a new set of well-defined Raman peaks at ~823, 856, 920 and 968 cm<sup>-1</sup> were observed. Comparing these peaks with the Raman features of natural Si-free MgAl<sub>2</sub>O<sub>4</sub>-spinel, synthetic Si-free MgAl<sub>2</sub>O<sub>4</sub>-spinel, natural low quartz, synthetic coesite, synthetic stishovite and synthetic forsterite, we infer that they should belong to the SiO<sub>4</sub> groups. The correlations between the Raman intensities and SiO<sub>2</sub> contents of the Si-bearing MgAl<sub>2</sub>O<sub>4</sub>-spinel suggest that at some P-T conditions some Si cations must start to adopt the M-site and form SiO<sub>6</sub> groups. Unlike the SiO<sub>4</sub> groups with very intense Raman signals, the SiO<sub>6</sub> groups are largely Raman-silent.

Our experimental data suggest that the Si cations in the MgAl<sub>2</sub>O<sub>4</sub>-spinel primarily appear on the T-site at P-T conditions < ~3-4 GPa and 1500 °C, but soon attain a random

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distribution between the T-site and M-site of the MgAl<sub>2</sub>O<sub>4</sub>-  
spinel at P-T conditions > ~5-6 GPa and 1630-1650 °C.